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Transport properties of a Luttinger liquid in the presence of several time-dependent impurities

D. Makogon, V. Juricic, and C. Morais Smith
Institute for Theoretical Physics, University of Utrecht,
Leuvenlaan 4, 3584 CE Utrecht, The Netherlands.

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We study the transport properties of a Luttinger liquid in the presence of several time-dependent weak point-like impurities. Our starting point is the bosonized form of the Luttinger liquid Hamiltonian with a potential introduced by the impurities. We find the correction to the total current due to the backscattering of the electrons by the impurities in first order of perturbation theory for a general time-dependent impurity potential. We then apply this result to a single time-dependent impurity, and show that it reproduces the result obtained by Feldman and Gefen in Ref. 7, in particular that the current enhancement occurs only for strong repulsive electron-electron interactions. For the case of two impurities oscillating with the same frequency, we find a novel effect, namely, that the dc-component of the backscattering current is positive *even for weak repulsive interactions*, due to the presence of the interference term induced by spatial correlations in the Luttinger liquid. We show that the impurity frequencies at which the enhancement takes place form a band-like structure. In the case of several impurities, the bands become broader, because of interference effects.

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I. INTRODUCTION

The effect of impurities on the transport properties of low-dimensional systems has attracted a great deal of attention during the last years. In a pioneer work, Kane and Fisher showed that the transport of a one-channel Luttinger liquid through a barrier is strikingly different from that in a Fermi-liquid consisting of non-interacting electrons.[1] Using a renormalization group technique, they have shown that the behavior depends crucially on whether the electron-interactions are repulsive or attractive. For repulsive interactions, $g < 1$, the barrier is relevant, and arbitrary small ones lead to complete reflection at zero temperature. On the other hand, for attractive interactions, $g > 1$, the barrier is an irrelevant perturbation and transmission is perfect through even the largest barriers. Non-interacting electrons ($g = 1$) exhibit a behavior intermediate between these two limits because in this case the barrier is a marginal perturbation.

Later, the resonant tunneling of a single-channel interacting electrons through a double barrier was considered and the time-dependence of the width of the resonances was discussed.[2,3] In addition, a Hall bar with two weak barriers was proposed as an appropriate device for measuring the fractional charge in the quantum Hall effect.[4] However, in all those works, the barriers were considered to be static.

Recently, the transport in a Luttinger liquid in the presence of a time-dependent impurity was considered.[5,6,7,8] The model may describe a constricted quantum wire or a constricted Hall bar at $\nu = 1/(2n+1)$ with a time-dependent voltage at the constriction.[9] In particular, Feldman and Gefen[7] have found an enhancement of the conductance beyond the value of the quantum of conductance, $G_0 = e^2/h$, for strong repulsive electron-electron interactions, $g < 1/2$.

In this paper we study the effect of several *time-dependent* barriers on the transport in an otherwise perfect one-channel Luttinger liquid. We find that due to the interference term between the impurities, the conductance can be enhanced *also for weak repulsive interactions*, $1/2 < g < 1$. In the appropriate limits, our work reproduces the previous known results for a *single time-dependent* impurity,[7] and for *several static* impurities.[4] The model is based on the bosonization formalism and the calculations are performed using perturbation theory and the Keldysh technique.

The structure of the paper is the following: in section II we present our model and derive a general expression for the increase of the dc current beyond the quantized value G_0. We consider only the backscattering contribution and restrict ourselves to the lowest order of the perturbation theory, in which, as it is well-known, forward scattering has no effect on the conductance of one-dimensional systems. In section III we compare our results with the ones for a single impurity,[7] and in section IV we discuss the multi-impurity case, with an emphasis on the simplest case of a double-barrier structure, where the novel features are already present. Our conclusions are drawn in section V.

II. THE MODEL

In this section we study the transport properties of a one-dimensional quantum wire in the presence of several time-dependent impurities located at positions x_p, $p = 1, ..., N$. We consider spinless electrons and concentrate on the zero-temperature case. Using the bosonization technique, the action of the model reads[7,10,11]

$$
\begin{aligned}
S &= \int dt dx \left\{ \frac{1}{8\pi} \left[(\partial_t \hat{\Phi})^2 - v_F^2 (\partial_x \hat{\Phi})^2 \right] \right. \qquad (1) \\
&- \left. \sum_p \delta(x - x_p) W_p(t) \left(e^{i\sqrt{g}\hat{\Phi}(t,x_p)} e^{i\omega_0 t} + H.c. \right) \right\},
\end{aligned}
$$

where the bosonic field Φ is related to the charge density $\hat{\rho} = e\sqrt{g}\partial_x \hat{\Phi}/2\pi$, $\omega_0 = eV/\hbar$ is the Josephson frequency associated with the external voltage V, $W_p(t)$ is an arbitrary pumping function, which controls the time dependence of the impurity potential, v_F is the Fermi velocity, and g measures the strength of the electron-electron interactions. In the following, we set the Planck constant $\hbar = 1$ and the Fermi velocity $v_F = 1$.

We begin our analysis by introducing the backscattering impurity operator

$$
\hat{B}(t) \equiv \sum_p W_p(t) e^{i\sqrt{g}\hat{\Phi}(t,x_p)} e^{i\omega_0 t}. \qquad (2)
$$

The operator for the backscattering current then reads

$$
\hat{I}_{bs} = -i\hat{B}(t) + H.c. \qquad (3)
$$

In order to find the backscattering current at time t, we must evaluate the expectation value

$$
\langle \hat{I}_{bs} \rangle = \langle 0 | S(-\infty; t) \hat{I}_{bs} S(t; -\infty) | 0 \rangle, \qquad (4)
$$

where $\langle 0|$ denotes the initial state, and S is the scattering matrix. To the lowest order in W,

$$
\begin{aligned}
S(t; -\infty) &= 1 - i \int_{-\infty}^{t} dt' [\hat{B}(t') + H.c.], \\
S(-\infty; t) &= S^*(t; -\infty). \qquad (5)
\end{aligned}
$$

Substituting then Eqs. (5) into Eq. (4) and keeping only the terms of order W^2 and zero total charge we obtain

$$
I_{bs}(t) = \int_{-\infty}^{t} dt' \langle 0 | \hat{B}^*(t') \hat{B}(t) - \hat{B}(t') \hat{B}^*(t) + H.c. | 0 \rangle, \qquad (6)
$$

where

$$
\langle 0 | \hat{B}^*(t') \hat{B}(t) | 0 \rangle = \sum_{k,j} W_k(t') W_j(t) e^{i\omega_0 (t-t')} \mathcal{J}_{kj},
$$

$$
\begin{aligned}
\mathcal{J}_{kj} &\equiv \langle 0 | e^{-i\sqrt{g}\hat{\Phi}(t',x_k)} e^{i\sqrt{g}\hat{\Phi}(t,x_j)} | 0 \rangle \\
&= e^{g \langle 0 | \hat{\Phi}(t',x_k) \hat{\Phi}(t,x_j) | 0 \rangle}. \qquad (7)
\end{aligned}
$$

The Green function of the Bose field reads

$$
\begin{aligned}
\langle 0 | \hat{\Phi}(t',x_k) \hat{\Phi}(t,x_j) | 0 \rangle = &- \ln[\delta + i(t' - t + x_k - x_j)] \\
&- \ln[\delta + i(t' - t + x_j - x_k)],
\end{aligned}
$$

where δ is infinitesimal. Defining now the new variable $\tau = t - t'$, the backscattering current acquires the form

$$
\begin{aligned}
I_{bs}(t) = &\int_0^\infty d\tau [e^{i\omega_0 \tau} - H.c.] \sum_{k,j} W_k(t - \tau) W_j(t) \\
&\times \{[\delta + i(\tau + x_k - x_j)]^{-g} [\delta + i(\tau + x_j - x_k)]^{-g} - H.c.\}.
\end{aligned}
$$

Because δ has an infinitesimally small value, $\mathrm{Im}\{[(x_k - x_j)^2 - \tau^2]^{-g}\} = 0$, for $|x_k - x_j| \geq \tau$. In addition, $\mathrm{Im}[(-1)^{-g}] = \mathrm{Im}[e^{-i\pi g}] = -\sin \pi g$, and we eventually obtain

$$
I_{bs}(t) = C \sum_{k,j} \int_{|x_k - x_j|}^{\infty} d\tau \frac{\sin(\omega_0 \tau) W_k(t - \tau) W_j(t)}{|\tau^2 - (x_k - x_j)^2|^g}, \qquad (8)
$$

where $C = -4\sin(\pi g)$. Eq. (8) is one of the main results of this paper. It yields in lowest order of perturbation theory the backscattering current of a Luttinger liquid in the presence of an arbitrary number of time-dependent impurities, each of them providing a scattering potential defined by a function $W_j(t)$.

We can progress further in the analytical calculation of some specific examples by introducing a simplifying assumption, namely, that the impurity potential is a periodic function of time, $W_j(t) = W_j \cos(\Omega_j t + \varphi_j)$. In this case, the numerator in the integral in Eq. (8) reads

$$
\begin{aligned}
&\sin(\omega_0 \tau) W_k(t - \tau) W_j(t) = (W_j W_k / 4) \\
&\times \ \{\sin[(\omega_0 - \Omega_k)\tau + (\Omega_k + \Omega_j)t + \varphi_k + \varphi_j] \qquad (9) \\
&+ \ \sin[(\omega_0 + \Omega_k)\tau - (\Omega_k + \Omega_j)t - \varphi_k - \varphi_j] \\
&+ \ \sin[(\omega_0 - \Omega_k)\tau + (\Omega_k - \Omega_j)t + \varphi_k - \varphi_j] \\
&+ \ \sin[(\omega_0 + \Omega_k)\tau - (\Omega_k - \Omega_j)t - \varphi_k + \varphi_j]\},
\end{aligned}
$$

indicating that in order to obtain a nonzero dc-component of the current, it is necessary to have at least two modes with the same frequency. Let us now define

$$
F_g(\omega, x, \varphi) \equiv \sin(\pi g) \int_{|x|}^{\infty} d\tau \frac{\sin(\omega \tau + \varphi)}{|\tau^2 - x^2|^g}, \qquad (10)
$$

which can be explicitly evaluated, and reads

$$
\begin{aligned}
F_g(\omega, x, \varphi) &= \frac{\sin(\pi g)}{2^{3/2-g}} \left| \frac{\omega}{x} \right|^{g-1/2} \left\{ 2\Gamma\left(\frac{1}{2} + g\right) \Gamma(1 - 2g) \right. \\
&\times \ J_{g-1/2}(|\omega x|) \mathrm{sgn}(\omega) \cos[\varphi - \mathrm{sgn}(\omega)\pi g] \\
&+ \left. \Gamma\left(g - \frac{1}{2}\right) \Gamma(2 - 2g) J_{1/2-g}(|\omega x|) \sin(\varphi) \right\},
\end{aligned}
$$

where $J_\alpha(x)$ are Bessel functions of the first kind. Assuming that the impurities oscillate with the same frequency, $\Omega_k \equiv \Omega$, we find that for each term $< k, j >$ in the sum there is a counterterm $< j, k >$ with opposite phase. Hence, the contribution to the dc current contains terms of the following form,

$$
\sin(\omega \tau + \varphi) + \sin(\omega \tau - \varphi) = 2 \sin(\omega \tau) \cos(\varphi),
$$

yielding,

$$\begin{aligned} I_{dc} &= -\sum_{k,j} W_k W_j \cos(\varphi_j - \varphi_k) \left[F_g\left(\omega_0 + \Omega, x_k - x_j, 0\right)\right. \\ &+ \left. F_g\left(\omega_0 - \Omega, x_k - x_j, 0\right)\right]. \end{aligned} \tag{11}$$

Therefore, the dc component of the backscattering current generated by a set of dynamical impurities oscillating with a frequency Ω can be expressed, in first order of perturbation theory, in terms of the dc current for a set of static impurities

$$I_{dc} = \frac{1}{2}[I_{st}(\omega_0 + \Omega) + I_{st}(\omega_0 - \Omega)], \tag{12}$$

where the dc current for a set of static impurities reads

$$I_{st}(\omega) = -\sum_{k,j} W_k W_j \cos(\varphi_j - \varphi_k) F_g\left(\omega, x_k - x_j, 0\right). \tag{13}$$

The above form of the dc current generalizes the result obtained by Feldman and Gefen in Ref. 7 for the case of one impurity. Eq. (13) extends the result obtained by Chamon *et al.* in Ref. 4 for the dc component of the backscattering current generated by a set of static impurities. It is worth noting here that the function $I_{st}(\omega)$ is odd, $I_{st}(-\omega) = -I_{st}(\omega)$, and can be represented as a product of a dimensional factor and a function of dimensionless variables ωx_k, since

$$F_g(\omega, x, 0) \sim |x|^{1-2g} |\omega x|^{g-1/2} J_{g-1/2}(|\omega x|). \tag{14}$$

The dimensionless part remains invariant with scaling

$$\omega \to \omega' = \omega\eta, \quad x_k \to x'_k = x_k/\eta, \forall k, \tag{15}$$

whereas both currents I_{st} and I_{dc} scale with the dimensional factor

$$I_{st}(\omega, \{x_k\}) \to I_{st}(\omega', \{x'_k\}) = \eta^{2g-1} I_{st}(\omega, \{x_k\}). \tag{16}$$

This leads to a conclusion that the inter-impurity separation can be fixed without any loss of generality, i.e., the dependence of the dc current on the inter-impurity separation is the same as on the Josephson frequency, ω_0, up to a factor, which is a power of the distance between the impurities. Therefore, by fixing the distance between the impurities and considering the dependence of the dc current on the Josephson frequency, we can also obtain the dependence of the dc current on the distance between the impurities, as a consequence of the scaling transformation, given by Eq. (15).

III. SINGLE TIME-DEPENDENT IMPURITY

This case has already been discussed in the literature, see Refs. 5,7. Here, we follow the notation of Refs. 7,10, and calculate the dc contribution I_{dc} to the total current $I = I_{dc} + I_{ac}$, for the sake of completeness, as well as to show that our model correctly reproduces the well-known limit. Defining $W_j \equiv U$ and using Eq. (13), we may express the dc current for one static impurity as

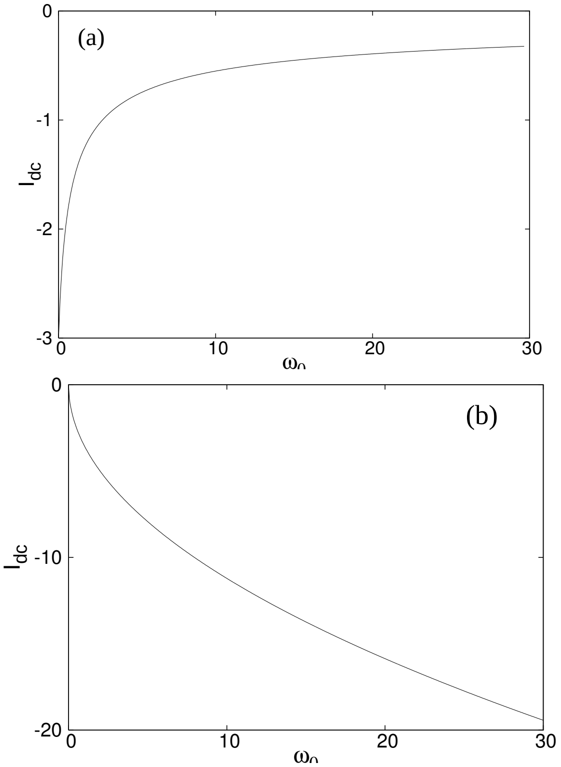

Figure 1: I_{dc} versus ω_0 for one static impurity with $U = 1$. (a) $g = 1/4$. (b) $g = 3/4$.

$$I_{st}(\omega_0) = -2U^2 F_g\left(\omega_0, 0, 0\right), \tag{17}$$

where the function $F_g\left(\omega_0, 0, 0\right)$ can be determined using asymptotic properties of Bessel functions for small values of the argument,

$$I_{st}(\omega_0) = -U^2 \mathrm{sgn}(\omega_0) \Gamma(1-2g) \sin(2\pi g) |\omega_0|^{2g-1}. \tag{18}$$

This function is plotted in Fig. 1 for different values of the interaction strength, g, and we set $U = 1$. Using Eq. (12), the dc component of the backscattering current generated by the presence of a single time-dependent impurity reads

$$\begin{aligned} I_{dc} &= \frac{U^2}{2} \Gamma(1-2g) \sin(2\pi g) [(\Omega - \omega_0)^{2g-1} \\ &- (\Omega + \omega_0)^{2g-1}], \quad \Omega > \omega_0, \end{aligned} \tag{19}$$

$$\begin{aligned} I_{dc} &= -\frac{U^2}{2} \Gamma(1-2g) \sin(2\pi g) [(\omega_0 - \Omega)^{2g-1} \\ &+ (\Omega + \omega_0)^{2g-1}], \quad \Omega < \omega_0, \end{aligned} \tag{20}$$

which is in agreement with Ref. 7, after replacing the dimensionless variables by the dimensional ones. The correction to the conductance may also be promptly evaluated,

$$\Delta G = \frac{dI_{dc}}{dV}\Big|_{V=0} = \frac{e}{\hbar} \frac{dI_{dc}}{d\omega_0}\Big|_{\omega_0 = 0}, \tag{21}$$

which yields

$$\Delta G = \frac{eU^2}{\hbar}(1-2g)\Gamma(1-2g)\sin(2\pi g)\Omega^{2g-2}. \qquad (22)$$

The interesting result for the time-dependent single-impurity case[7] is that at strong repulsive interactions, $g < 1/2$, the backscattering current becomes positive for $\Omega > \omega_0$, thus leading to an increase of the conductance, in comparison with the impurity-free value, $G_0 = e^2/h$. The ac contribution to the current may be analogously calculated using

$$I_{ac} = -U^2 \lim_{d\to 0} \left[F_g\left(\omega_0 - \Omega, d, 2\Omega t\right) + F_g\left(\Omega + \omega_0, d, -2\Omega t\right)\right],$$

which yields

$$\begin{aligned} I_{ac}(t) &= U^2\Gamma(1-2g)\sin(\pi g)\cos(\pi g + 2\Omega t) \\ &\times \ [(\Omega-\omega_0)^{2g-1} - (\Omega+\omega_0)^{2g-1}], \quad \Omega > \omega_0, \\ I_{ac}(t) &= -U^2\Gamma(1-2g)\sin(\pi g)[\cos(\pi g - 2\Omega t)(\omega_0-\Omega)^{2g-1} \\ &+ \ \cos(\pi g + 2\Omega t)(\Omega+\omega_0)^{2g-1}], \quad \Omega < \omega_0. \end{aligned}$$

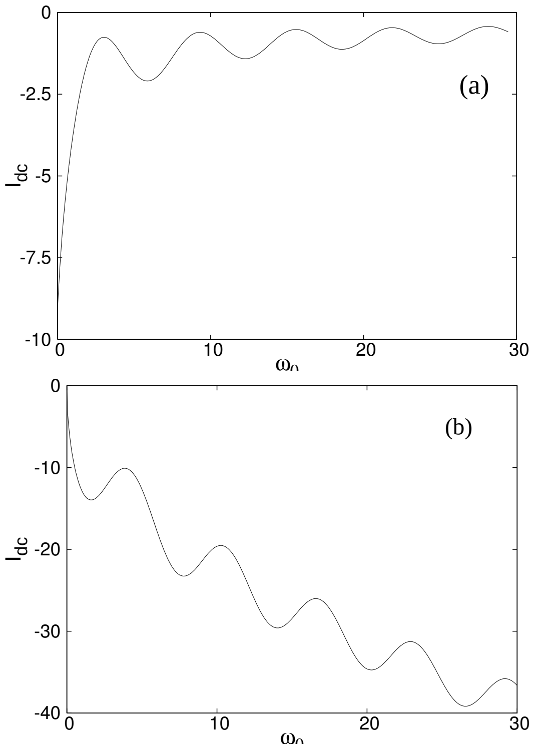

Figure 2: I_{dc} versus ω_0 for two static impurities with $L = 1$ and $U = 1$. (a) $g = 1/4$. (b) $g = 3/4$.

IV. SEVERAL TIME-DEPENDENT IMPURITIES ON A LATTICE

In this section we first concentrate on the simplest case involving more than one impurity, namely, the case of two time-dependent impurities separated by the distance L. We consider the case when the two impurities oscillate with the same frequency, Ω, and allow for a phase shift between them. Let us first analyze the dc current contribution to the total backscattering current as a function of the Josephson frequency ω_0 associated with the external voltage V for two static impurities (considered before by Chamon *et al.* in Ref. 4 for $g \le 1/2$). In this case, Eq. (11) yields

$$I_{st}(\omega_0) = I_{st}^{(1)}(\omega_0) + I_{st}^{(2)}(\omega_0) + I_{st}^{int}(\omega_0), \qquad (23)$$

where the first two terms are the dc currents for the single impurity 1 and 2, respectively, given by Eq. (18), and the interference term reads

$$I_{st}^{int}(\omega_0) = -4W_1W_2\cos\varphi F_g\left(\omega_0, L, 0\right). \qquad (24)$$

After including the functions F_g defined in Eq. (10), we obtain the explicit form of the interference term

$$\begin{aligned} I_{st}^{int}(\omega_0) &= -2W_1W_2\,\mathrm{sgn}(\omega_0)\cos(\varphi)L^{1-2g} \qquad (25) \\ &\times \ \frac{\pi\Gamma(1/2+g)}{2^{1/2-g}\Gamma(2g)}|\omega_0 L|^{g-1/2}J_{g-1/2}(|\omega_0 L|), \end{aligned}$$

where we used the following identity

$$\sin(2\pi g)\Gamma(1-2g)\Gamma(2g) = \pi.$$

For small distances $\omega_0 L \ll 1$ the case of two impurities reduces to the above-considered single impurity case with an effective amplitude of the impurity potential $U^2 = W_1^2 + W_2^2 + 2W_1W_2\cos(\varphi)$, which results from the asymptotic property of the Bessel function

$$\lim_{x\to 0} |x|^{1/2-g}J_{g-1/2}(|x|) = \frac{2^{1/2-g}}{\Gamma(1/2+g)}. \qquad (26)$$

Let us now plot Eq. (23) to render the results more visible. We first consider two impurities with equal amplitudes of the potential, $W_1 = W_2 = U$, and without the phase shift, $\varphi = 0$, to simplify the problem. We plot in Fig. 2 the dc current for two static impurities as a function of ω_0. In Fig. 2a, the interaction strength, $g = 1/4$, whereas in Fig. 2b $g = 3/4$. As it was argued above, fixing $L = 1$ does not lead to any loss of generality, since the value of the current for some other length can be obtained by scaling. Comparing Fig. 1 and Fig. 2 we can conclude that the interference term modifies the dc current in a way that it becomes a non-monotonous function of the external voltage. The dc current for the two impurities oscillating with the same frequency Ω can now be readily obtained using the result for the static impurities, Eqs. (23) and (24), and Eq. (12), which relates the current for the dynamical and the static impurities.

The dependence of I_{dc} on Ω and ω_0 can be better observed in a 3D plot, see Fig. 3a. In Fig. 3b we selected only the positive contribution in order to facilitate the visualization of the region where the novel effects arise.

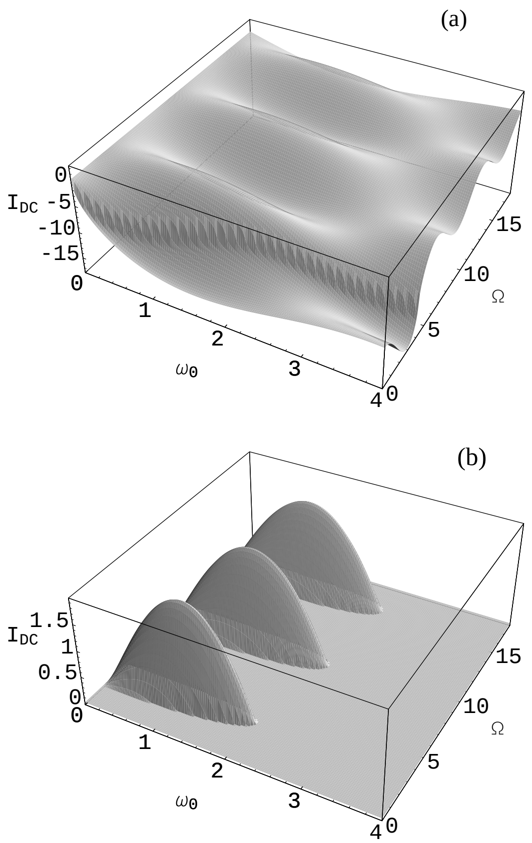

Figure 3: (a) Dependence of the dc current on the Josephson frequency, ω_0, and the impurity frequency, Ω, for two impurities with $L = 1$, $U = 1$, and $g = 3/4$. (b) the region with a positive dc current, $I_{dc} > 0$.

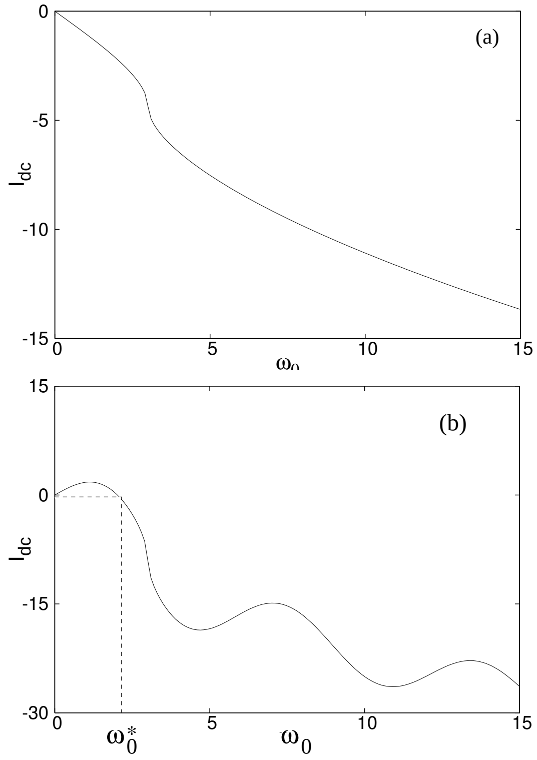

Figure 4: I_{dc} versus ω_0 for $g = 3/4$, $\Omega = 3$, and $U = 1$. (a) one impurity. (b) two impurities with $L = 1$.

Let us first notice that the backscattering current enhances the total current *even for weaker* ($g > 1/2$) repulsive interactions, see Fig. 3b. The impurity frequency at which this effect arises coincides with the Josephson frequency at which the current for the static impurities has a positive slope, see Fig. 2b. This result contrasts with the one obtained for the single time-dependent impurity, where no positive contribution exists for $g > 1/2$, since the dc current for a single static impurity monotonously decreases with the Josephson frequency, see Fig. 4a. On the other hand, the presence of the interference term in the case of two impurities gives rise to a more complicated non-monotonous behavior of the current with the external voltage, which leads to an enhancement of the total current even for weak repulsive interactions.

For illustrative purposes we consider a particular section of the 3D plot in Fig. 3a defined by the plane $\Omega = 3$ for the novel case where there is an increase of the current, namely, $g = 3/4$. The dc current dependence on the Josephson frequency, shown in Fig. 4b, indicates that the total current is increased for small values of ω_0. Beyond a critical value ω_0^* the current becomes negative, and at $\omega_0 = \Omega$ a step can be observed.

This effect can be understood by considering the relationship between the dc currents for the time-dependent and the static impurities. Recalling that $I_{st}(\omega)$ is an odd function, we may rewrite Eq. (12) as

$$I_{dc} = \frac{1}{2}[I_{st}(\Omega + \omega_0) - I_{st}(\Omega - \omega_0)]. \tag{27}$$

For a positive dc-component of the backscattering current, $I_{dc} > 0$, the previous equation implies

$$I_{st}(\omega_0 + \Omega) > I_{st}(\Omega - \omega_0). \tag{28}$$

The odd function $I_{st}(\omega)$ is negative for positive arguments, the inequality can thus only hold if $\Omega - \omega_0 > 0$, since for $\Omega - \omega_0 < 0$, the function I_{st} is positive, $I_{st}(\Omega - \omega_0 < 0) > 0$. In the one-impurity case, the function $I_{st}(\omega)$ monotonously increases with ω for $g < 1/2$, hence the inequality (28) holds for $\Omega > \omega_0$, resulting in a positive dc current. On the other hand, for weak repulsive interactions, $g > 1/2$, the current I_{st} is a decreasing function of its argument, the inequality (28) is not obeyed, and, consequently, the dc-component of the backscattering current is negative. In the case of two impurities, the function I_{st} is non-monotonous even for weak repulsive interactions, $g > 1/2$, meaning that there are intervals of frequency in which the function I_{st} increases. If the frequency of the impurity belongs to one of such intervals, according to Eq. (28), the total current is increased, at least for a small Josephson frequency, $\omega_0 \ll \Omega$. This effect arises as a consequence of the interference term, given by Eq. (25), which results from the spatial correlations in the Luttinger liquid that influence the backscattering current due to the presence of two point-like impurities.

In general, for any number of weak impurities, the dc-component of the backscattering current is positive, if for some frequencies $0 < \omega_1 < \omega_2$, the static current obeys

$$I_{st}(\omega_1) < I_{st}(\omega_2). \tag{29}$$

The corresponding positive value of the dc current, according to Eq. (12), reads

$$I_{dc} = \frac{1}{2}[I_{st}(\omega_2) - I_{st}(\omega_1)] = \frac{1}{2}[|I_{st}(\omega_1)| - |I_{st}(\omega_2)|], \tag{30}$$

where the frequencies ω_1 and ω_2 are related to the Josephson frequency, ω_0, and the frequency of the impurity potential, Ω, as follows

$$\Omega = \frac{1}{2}(\omega_2 + \omega_1), \quad \omega_0 = \frac{1}{2}(\omega_2 - \omega_1). \tag{31}$$

The criterium for a positive dc-component of the backscattering current, given by Eq. (29), implies that there exists an interval of frequencies where the static current increases. Then for the impurity frequency, Ω, belonging to such an interval, and the Josephson frequency $\omega_0 \ll \Omega$, using Taylor expansion of the static current, I_{st}, in Eq. (27) and keeping only the linear term in Josephson frequency, we obtain

$$I_{dc} = I'_{st}(\Omega)\omega_0 + \mathcal{O}(\omega_0^2). \tag{32}$$

Therefore, in the case of weak impurities when the expansion to the lowest order of perturbation theory is valid, the backscattering current is positive for any frequency of the impurity potential, Ω, such that the static current has a positive slope, $I'_{st}(\Omega) > 0$, and the Josephson frequencies $\omega_0 \ll \Omega$. However, this is not the most general situation, since it may occur, depending on the form of the static current, that for some frequency Ω, the static current decreases, $I'_{st}(\Omega) < 0$, but the frequency ω_0 is such that the inequality (28) is still obeyed.

Let us now return to the case of two impurities, where, as we will show below, the increase of the total current occurs only for the frequencies of the impurity potential at which the static current increases. The static current in this case is such that for two consecutive local minima and local maxima, $\omega_{min1} < \omega_{max1} < \omega_{min2} < \omega_{max2}$, it obeys $I_{st}(\omega_{max1}) > I_{st}(\omega_{min1}) > I_{st}(\omega_{max2}) > I_{st}(\omega_{min2})$, see Fig. 2b. Then, the maximal current enhancement reads

$$I_{dc} = \frac{1}{2}[I_{st}(\omega_{max1}) - I_{st}(\omega_{min1})]. \tag{33}$$

The corresponding frequency of the impurity potential and the Josephson frequency are given by Eq. (31) with $\omega_1 \equiv \omega_{min1}$ and $\omega_2 \equiv \omega_{max1}$. In the case of two impurities, the current enhancement $I_{dc} > 0$ occurs only for the impurity frequencies Ω such that $I'_{st}(\Omega) > 0$, since the static current decreases faster than it increases. Moreover, due to the quasi-periodicity of the function I_{st}, each interval of frequencies where $I'_{st}(\Omega) > 0$ is followed by an interval with $I'_{st}(\Omega) < 0$ in which the current enhancement never occurs. Therefore, the set of impurity frequencies such that the dc-component of the backscattering current is positive has a band-like structure. Finally, for a fixed impurity frequency, the maximum value of the Josephson frequency, ω_0^*, for which is possible to observe the current enhancement is limited to the maximal ω_0 such that $I_{st}(\Omega - \omega_0) = I_{st}(\Omega + \omega_0)$.

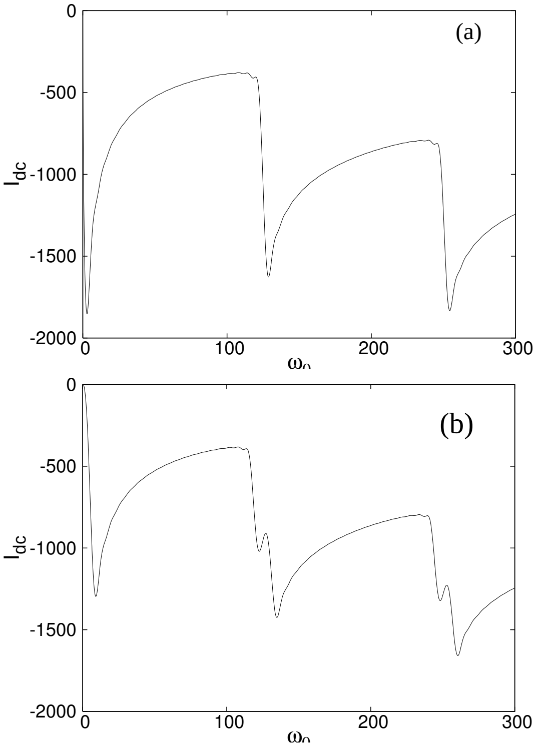

Figure 5: I_{dc} versus ω_0 for $N = 20$ static impurities homogenously distributed on a lattice with the length $L = 1$ and with the phase shift $\Delta\varphi$, for $g = 3/4$ and $U = 1$. (a) $\Delta\varphi = 0$. (b) $\Delta\varphi = \pi/10$.

We now discuss the dc current for N time-dependent impurities homogeneously distributed on a lattice, and separated from each other by the distance $d = L/(N-1)$, in the case of weak repulsive interactions, $g > 1/2$. Since the dc current for the dynamical impurities is related to the current for the static ones, Eq. (12), in the following we only consider the latter. In this case, the current consists of N single-impurity contributions and an additional term, which is a sum of the interference currents over all possible pairs of impurities. The interference term of a pair of impurities, located at x_j and x_k, given by Eq. (24), is quasi-periodic in frequency with period $2\pi/|x_j - x_k|$. As we discussed above, the values of the impurity frequency where an increase of the dc-current occurs form a band-like structure, and thus the values of Ω for which $I_{dc} > 0$ in the case of N impurities are determined from the overlap of the bands for each pair of impurities. This overlap occurs within the frequency range determined by the widest band formed by the pairs of impurities, which is the one for the two nearest-neighboring impurities, and thus has the period $2\pi/d$. The frequency dependence of the dc current is displayed in Fig. 5a for $N = 20$ impurities homogeneously distributed on a lattice with the length $L = 1$. It shows that the frequency region with positive dc current is approximately 20 times larger than in the case of two impurities, in agreement with the above arguments. Finally, in Fig. 5b we observe that a finite phase shift between the impurities leads to the appearance of a new region where the function $I_{st}(\omega_0)$ increases, and thus generates new bands with a positive dc component of the backscattering current.

V. CONCLUSIONS

In this work, we studied the transport properties of a Luttinger liquid in the presence of several weak time-dependent point-like impurities. Our approach is based on the bosonized version of the Luttinger liquid Hamiltonian, in which we considered the current of the electrons backscattered by the impurities in lowest order of perturbation theory. We first found the backscattering current induced by a set of weak impurities with an arbitrary time-dependent potential, and we then concentrated on the particular case of a periodic potential. The obtained form of the dc current for several impurities oscillating with the same frequency, given by Eq. (11), generalizes the result for a single dynamical impurity obtained by Feldman and Geffen in Ref. 7. Moreover, we showed that the dc current generated by a set of time-dependent impurities with a frequency Ω in the presence of an external voltage $\omega_0 = eV/\hbar$ reduces to the sum of the currents for static impurities subjected to an external voltage $|\omega_0 \pm \Omega|$, as described by Eq. (12). This result enabled us to reduce the problem of calculating the dc current of the dynamical impurities to the one of the static impurities.

We applied the result for the backscattering current to a single time-dependent point-like impurity, and showed that it reproduces the result obtained by Feldman and Gefen, i.e., that the current enhancement is only possible for strong repulsive interactions, $g < 1/2$. We then concentrated on two dynamical impurities. In this case, the presence of spatial correlations in the Luttinger liquid leads to a non-monotonous behavior of the static current, which, in turn, gives rise to a positive dc-component of the backscattering current *even for weak repulsive interactions*, $g > 1/2$. Using the form of the dc current for a set of dynamical impurities in terms of the corresponding static currents, given by Eq. (12), we found that for two dynamical impurities the current enhancement occurs only for the values of the impurity frequency for which the static current (13) has a positive slope, $I'_{st}(\Omega) > 0$. Due to the quasi-periodic form of the static current for two impurities, the values of the impurity frequency for which the total current is enhanced form a band-like structure. Finally, we considered several impurities homogeneously distributed on a lattice, and found that an increase of the total current also occurs for weak repulsive interactions, $g > 1/2$. The frequencies of the impurity potential at which the increase takes place have a band-like structure, as in the case of two impurities, but the width of the band scales with the number of impurities, for a fixed length of the lattice.

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